

# Gustavo M Dalpian

## List of Publications by Year in descending order

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96  
papers

2,962  
citations

186265

28  
h-index

175258

52  
g-index

96  
all docs

96  
docs citations

96  
times ranked

4134  
citing authors

#	ARTICLE	IF	CITATIONS
1	Intrinsic doping limitations in inorganic lead halide perovskites. <i>Materials Horizons</i> , 2022, 9, 791-803.	12.2	10
2	Machine Learning Study of the Magnetic Ordering in 2D Materials. <i>ACS Applied Materials &amp; Interfaces</i> , 2022, 14, 9418-9432.	8.0	35
3	Pressure-Induced Stabilization of Sodium Halide Perovskites. <i>Journal of Physical Chemistry C</i> , 2022, 126, 4248-4254.	3.1	0
4	High-throughput inverse design and Bayesian optimization of functionalities: spin splitting in two-dimensional compounds. <i>Scientific Data</i> , 2022, 9, 195.	5.3	2
5	Hole conductivity through a defect band in $\text{ZnGa}_4\text{O}_4$ . <i>Physical Review Materials</i> , 2022, 6, .	2.4	4
6	Entropy-driven stabilization of the cubic phase of $\text{MaPbI}_3$ at room temperature. <i>Journal of Materials Chemistry A</i> , 2021, 9, 1089-1099.	10.3	35
7	<i>Ab initio</i> atomistic description of temperature-induced phase changes: The cases of zirconia and Ti-Y-co-doped zirconia. <i>Physical Review Materials</i> , 2021, 5, .	2.4	2
8	MXene Phase with $\text{C}_3$ Structure Unit: A Family of 2D Electrides. <i>Advanced Functional Materials</i> , 2021, 31, 2100009.	14.9	13
9	Tailoring the Optical, Electronic, and Magnetic Properties of $\text{MAPbI}_3$ through Self-Assembled Fe Incorporation. <i>Journal of Physical Chemistry C</i> , 2021, 125, 15636-15646.	3.1	9
10	Different shapes of spin textures as a journey through the Brillouin zone. <i>Physical Review B</i> , 2021, 104, .	3.2	23
11	Influence of defects on antidoping behavior in $\text{SmNi}_3\text{O}_3$ . <i>Physical Review B</i> , 2021, 104, .	3.2	6
12	Realization of predicted exotic materials: The burden of proof. <i>Materials Today</i> , 2020, 32, 35-45.	14.2	29
13	<i>Ab Initio</i> Simulations and Materials Chemistry in the Age of Big Data. <i>Journal of Chemical Information and Modeling</i> , 2020, 60, 452-459.	5.4	28
14	The Rashba Scale: Emergence of Band Anti-crossing as a Design Principle for Materials with Large Rashba Coefficient. <i>Matter</i> , 2020, 3, 145-165.	10.0	21
15	Doping quantum materials: Defects and impurities in $\text{FeGa}_2$ . <i>Physical Review B</i> , 2020, 102, .	3.2	6
16	Inverse design of compounds that have simultaneously ferroelectric and Rashba cofunctionality. <i>Physical Review B</i> , 2020, 102, .	3.2	20
17	Iron and oxygen vacancies at the hematite surface: pristine case and with a chlorine adatom. <i>Physical Chemistry Chemical Physics</i> , 2020, 22, 25380-25389.	2.8	7
18	Insulator-Metal Transition in the $\text{Nd}_2\text{CoFeO}_6$ Disordered Double Perovskite. <i>Journal of Physical Chemistry C</i> , 2020, 124, 22733-22742.	3.1	5



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37	Changes in charge density vs changes in formal oxidation states: The case of Sn halide perovskites and their ordered vacancy analogues. <i>Physical Review Materials</i> , 2017, 1, .	2.4	43
38	Vacancies at LaAlO <sub>3</sub> thin films: A 2D electron gas at the surface. <i>Journal of Alloys and Compounds</i> , 2016, 684, 544-548.	5.5	8
39	Emergence of competing magnetic interactions induced by Ge doping in the semiconductor FeGa <sub>3</sub> . <i>Physical Review B</i> , 2016, 94, .	3.2	9
40	Charge storage in oxygen deficient phases of TiO <sub>2</sub> : defect Physics without defects. <i>Scientific Reports</i> , 2016, 6, 28871.	3.3	48
41	Effect of Charges on the Interaction of a Water Molecule with the Fe <sub>2</sub> O <sub>3</sub> (0001) Surface. <i>Journal of Physical Chemistry C</i> , 2016, 120, 11918-11925.	3.1	22
42	A search for the ground state structure and the phase stability of tantalum pentoxide. <i>Journal of Physics Condensed Matter</i> , 2016, 28, 035801.	1.8	27
43	$\text{DFT} + \text{U}$ Simulation of the $\text{Ti}_4\text{Mn}_7\text{O}_{15}$ phases studied using density functional theory. <i>Physical Review Applied</i> , 2015, 3, .	3.8	15
44	A systematic first-principles study of the tungsten trioxide polymorphs. <i>Physica Status Solidi (B): Basic Research</i> , 2015, 252, 2290-2295.	1.5	2
45	$\text{Ti}_n\text{Mn}_2\text{O}_n$ phases studied using density functional theory. <i>Physical Review B</i> , 2014, 90, .	3.3	1
46	Oxygen vacancies at the surface of SrTiO <sub>3</sub> thin films. <i>Journal of Applied Physics</i> , 2014, 115, 033710.	2.5	14
47	First principles investigations on the electronic structure of anchor groups on ZnO nanowires and surfaces. <i>Journal of Applied Physics</i> , 2014, 115, .	2.5	16
48	First-principles equation of state and phase stability of niobium pentoxide. <i>Computational Materials Science</i> , 2014, 81, 133-140.	3.0	59
49	Cobalt-doped ZnO nanocrystals: quantum confinement and surface effects from ab initio methods. <i>Physical Chemistry Chemical Physics</i> , 2013, 15, 15863.	2.8	12
50	Electronic, dielectric, and optical properties of the B phase of niobium pentoxide and tantalum pentoxide by first-principles calculations. <i>Physica Status Solidi (B): Basic Research</i> , 2013, 250, 1644-1650.	1.5	24
51	Conduction electron spin resonance in AlB <sub>2</sub> . <i>Journal of Physics Condensed Matter</i> , 2013, 25, 216001.	1.8	5
52	Pressure-induced metal-insulator transition and absence of magnetic order in FeGa <sub>3</sub> from a first-principles study. <i>Physical Review B</i> , 2012, 86, .	3.2	19
53	Surface-induced structural modification in ZnO nanoparticles. <i>Journal of Nanoparticle Research</i> , 2012, 14, 1.	1.9	5
54	Computational studies of doped nanostructures. <i>Reports on Progress in Physics</i> , 2011, 74, 046501.	20.1	52

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55	First-principles calculations of lattice-strained core-shell nanocrystals. <i>Physical Review B</i> , 2011, 84, .	3.2	21
56	Liquid separation by a graphene membrane. <i>Journal of Applied Physics</i> , 2010, 108, 113527.	2.5	14
57	Origin of FM Ordering in Pristine Micro- and Nanostructured ZnO. <i>Nano Letters</i> , 2010, 10, 1383-1386.	9.1	98
58	Surface and Quantum Confinement Effects in ZnO Nanocrystals. <i>Journal of Physical Chemistry C</i> , 2010, 114, 18293-18297.	3.1	53
59	Role of Confinement on Diffusion Barriers in Semiconductor Nanocrystals. <i>Physical Review Letters</i> , 2009, 102, 025901.	7.8	27
60	Ferrimagnetic Fe-doped GaN: An unusual magnetic phase in dilute magnetic semiconductors. <i>Physical Review B</i> , 2009, 79, .	3.2	27
61	Evidence for a subtle structural symmetry breaking in $\text{EuB}_6$ . <i>Journal of Physics Condensed Matter</i> , 2009, 21, 456007.	1.8	9
62	Surface magnetization in non-doped ZnO nanostructures. <i>Applied Physics Letters</i> , 2009, 94, .	3.3	74
63	Effects of Side-Chain and Electron Exchange Correlation on the Band Structure of Perylene Diimide Liquid Crystals: A Density Functional Study. <i>Journal of Physical Chemistry B</i> , 2009, 113, 5376-5380.	2.6	12
64	Barrier-free substitutional doping of graphene sheets with boron atoms: <i>Ab initio</i> calculations. <i>Physical Review B</i> , 2009, 79, .	3.2	63
65	Quantum confinement effects on Mn-doped InAs nanocrystals: A first-principles study. <i>Physical Review B</i> , 2008, 78, .	3.2	18
66	Carrier-induced enhancement and suppression of ferromagnetism in $\text{Zn}_{1-x}\text{Cr}_x\text{Te}$ and $\text{Ga}_{1-x}\text{Cr}_x\text{As}$ : origin of the spinodal decomposition. <i>New Journal of Physics</i> , 2008, 10, 113007.	2.9	8
67	Dalpián and Chelikowsky Reply:. <i>Physical Review Letters</i> , 2008, 100, .	7.8	28
68	Band coupling model of electron and hole mediated ferromagnetism in semiconductors: the case of GaN. , 2008, , .		6
69	Symmetry Considerations in CdSe Nanocrystals. <i>Nano Letters</i> , 2006, 6, 501-504.	9.1	31
70	Self-Purification in Semiconductor Nanocrystals. <i>Physical Review Letters</i> , 2006, 96, 226802.	7.8	613
71	Energetic Pinning of Magnetic Impurity Levels in Quantum-Confined Semiconductors. <i>Nano Letters</i> , 2006, 6, 2887-2892.	9.1	45
72	Study of Phase Selectivity of Organic~Inorganic Hybrid Semiconductors. <i>Chemistry of Materials</i> , 2006, 18, 2805-2809.	6.7	35

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73	Carrier-mediated stabilization of ferromagnetism in semiconductors: holes and electrons. <i>Physica Status Solidi (B): Basic Research</i> , 2006, 243, 2170-2187.	1.5	46
74	Phenomenological band structure model of magnetic coupling in semiconductors. <i>Solid State Communications</i> , 2006, 138, 353-358.	1.9	134
75	Novel Approach to Tuning the Physical Properties of Organic-Inorganic Hybrid Semiconductors. <i>Physical Review Letters</i> , 2006, 96, 026405.	7.8	52
76	Impurity-induced phase stabilization of semiconductors. <i>Applied Physics Letters</i> , 2006, 89, 011907.	3.3	20
77	Electron-mediated ferromagnetism and negative $s\text{-}d$ exchange splitting in semiconductors. <i>Physical Review B</i> , 2006, 73, .	3.2	23
78	Impurity-stabilized zinc-blende phase of wurtzite compounds. <i>Journal of Physics and Chemistry of Solids</i> , 2005, 66, 2008-2010.	4.0	2
79	Stabilization of Zinc-Blende Semiconductors Through 3d Impurities and Holes. <i>AIP Conference Proceedings</i> , 2005, , .	0.4	0
80	Electron-induced stabilization of ferromagnetism in $\text{Ga}_{1-x}\text{Gd}_x\text{N}$ . <i>Physical Review B</i> , 2005, 72, .	3.2	120
81	First-principles study of Mn-induced local magnetic moments in host semiconductors. <i>Physical Review B</i> , 2005, 71, .	3.2	23
82	Transition from ferromagnetism to antiferromagnetism in $\text{Ga}_{1-x}\text{Mn}_x\text{N}$ . <i>Journal of Applied Physics</i> , 2005, 98, 083905.	2.5	18
83	Photoinduced cation interstitial diffusion in II-VI semiconductors. <i>Physical Review B</i> , 2005, 72, .	3.2	14
84	Initial stages of Ge and Si growth near SB monoatomic steps on Si(100). <i>Physical Review B</i> , 2004, 70, .	3.2	3
85	Hole-Mediated Stabilization of Cubic GaN. <i>Physical Review Letters</i> , 2004, 93, 216401.	7.8	32
86	Adsorption of Mn atoms on the Si(100) surface. <i>Surface Science</i> , 2004, 566-568, 688-692.	1.9	9
87	Energetics and electronic structure of stacking faults in ZnO. <i>Physical Review B</i> , 2004, 70, .	3.2	85
88	Theoretical investigation of a possible $\text{Mn}_x\text{Si}_{1-x}$ ferromagnetic semiconductor. <i>Physical Review B</i> , 2003, 68, .	3.2	42
89	Ab initio calculations of vacancies in $\text{Si}_x\text{Ge}_{1-x}$ . <i>Applied Physics Letters</i> , 2002, 81, 3383-3385.	3.3	14
90	Vacancy-mediated diffusion in disordered alloys: Ge self-diffusion in $\text{Si}_{1-x}\text{Ge}_x$ . <i>Physical Review B</i> , 2002, 65, .	3.2	32

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91	Influence of surface degrees of freedom on the adsorption of Ge ad-atoms on Si(100). Computational Materials Science, 2001, 22, 19-23.	3.0	0
92	Theoretical STM images of Ge monomers and trimers on Si(100). Surface Science, 2001, 482-485, 507-511.	1.9	0
93	Adsorption of monomers on semiconductors and the importance of surface degrees of freedom. Physical Review B, 2001, 63, .	3.2	8
94	Ab initiodetermination of the atomistic structure ofSixGe1xalloy. Physical Review B, 2001, 64, .	3.2	57
95	Two-Atom Structures of Ge on Si(100): Dimers versus Adatom Pairs. Physical Review Letters, 2001, 87, 036104.	7.8	5
96	Initial stages of Ge growth on Si(100): ad-atoms, ad-dimers, and ad-trimers. Physica B: Condensed Matter, 1999, 273-274, 589-592.	2.7	10